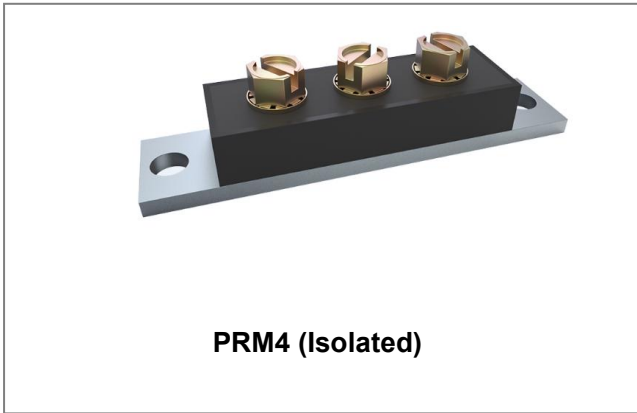


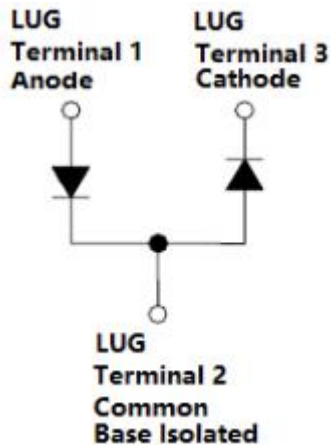
409DMQ135 409DMQ150 SCHOTTKY RECTIFIER



Features

- 175°C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Baseplate: Nickel plated; Terminals: Nickel plated
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- Reverse battery protection
- Converters
- UPS System
- Welding

Maximum Ratings:

Characteristics	Symbol	Condition	Max.		Units
			409DMQ135	409DMQ150	
Peak Repetitive Reverse Voltage	V _{RRM}	-	135	409DMQ135	V
Working Peak Reverse Voltage	V _{RWM}		150	409DMQ150	
DC Blocking Voltage	V _R				
Average Rectified Forward Current	I _{F(AV)}	50% duty cycle @T _c =105°C, rectangular wave form	200(Per Leg)		A
			400(Per Device)		
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I _{FSM}	8.3 ms, half Sine pulse	2760		A

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 200A, Pulse, T _J = 25 °C @ 400A, Pulse, T _J = 25 °C	0.91 1.10	1.03 1.21	V
	V _{F2}	@ 200A, Pulse, T _J = 125 °C @ 400A, Pulse, T _J = 125 °C	0.68 0.80	0.72 0.83	V
Reverse Current(Per Leg)*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.05	6	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	50	85	mA
Junction Capacitance(Per leg)	C _T	@V _R = 5V, T _C = 25 °C f _{sig} = 1MHz	5500	6000	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs
Isolation Voltage	V _{ISO}	Tracer to 1500V, measuring whether conducting base plate and the center column	-	1500	V

* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units	
Junction Temperature	T _J	-	-55 to +150	°C	
Storage Temperature	T _{stg}	-	-55 to +150	°C	
Typical Thermal Resistance Junction to Case(Per leg)	R _{θJC}	DC operation	0.40	°C/W	
Typical Thermal Resistance Junction to Case(Per package)	R _{θJC}	DC operation	0.20	°C/W	
Typical Thermal Resistance, case to Heat Sink	R _{θcs}	Mounting surface, smooth and greased	0.10	°C/W	
Mounting Torque	T _M	-	Mounting Torque	24(min) 35(max)	Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	79	g	
Case Style	PRM4 Isolated				

Ratings and Characteristics Curves

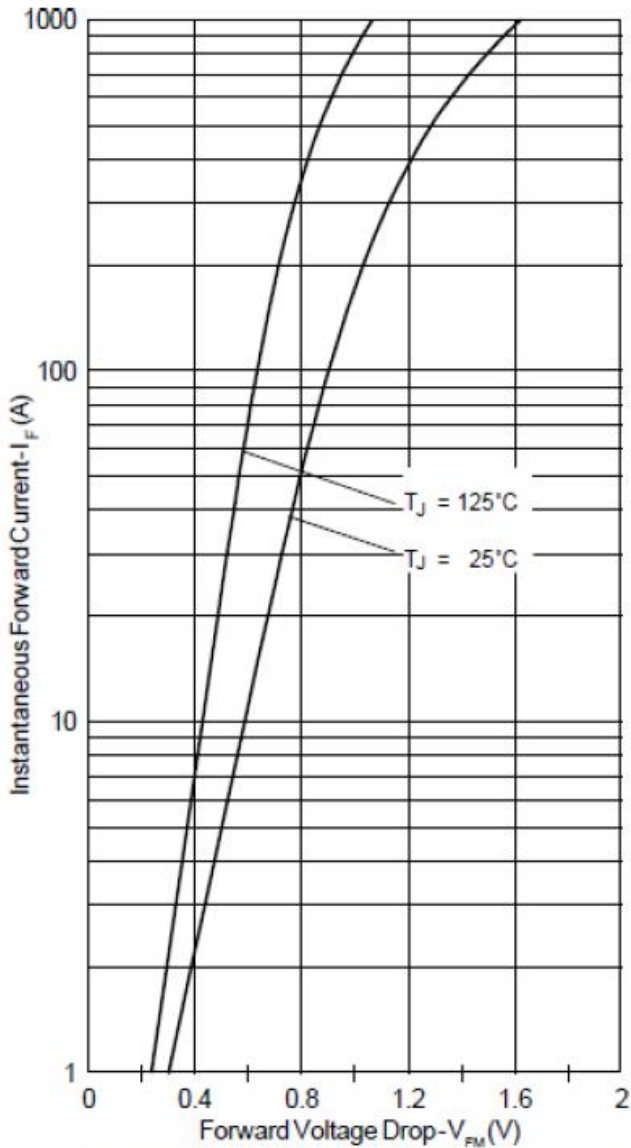


Fig. 1 - Max. Forward Voltage Drop Characteristics

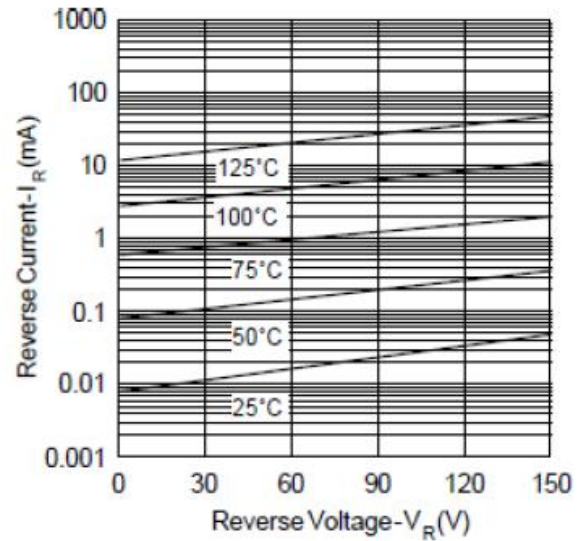


Fig. 2 - Typical Reverse Characteristics

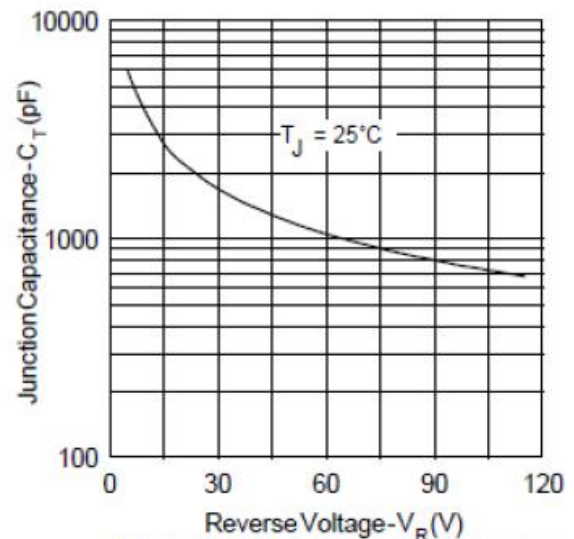
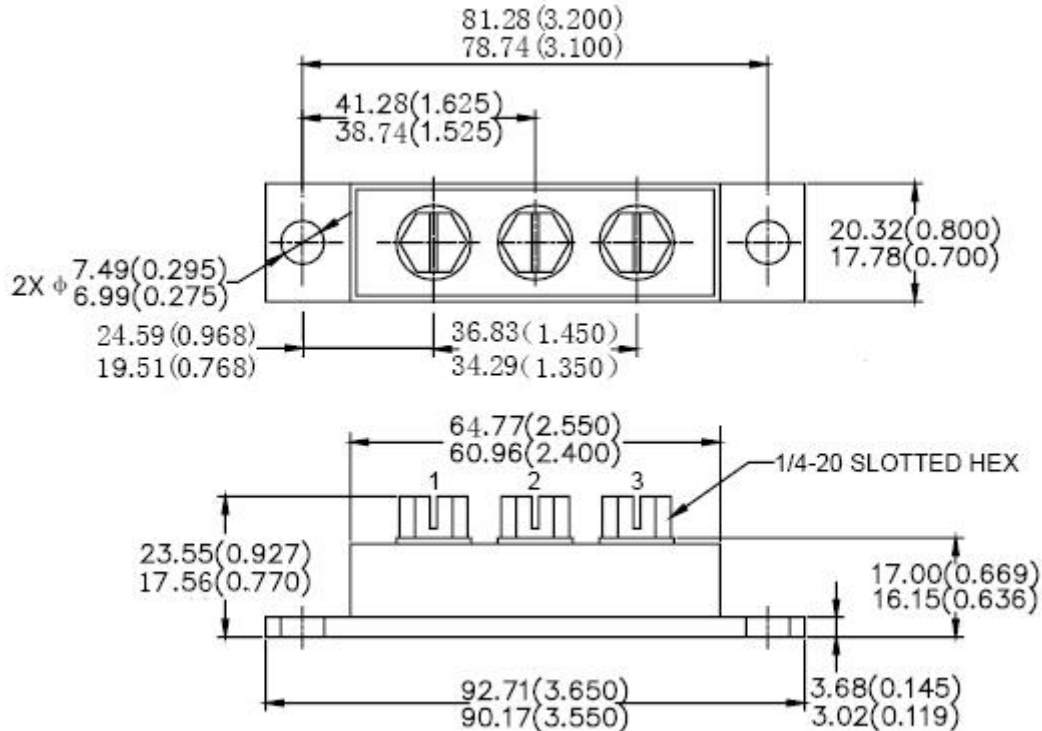


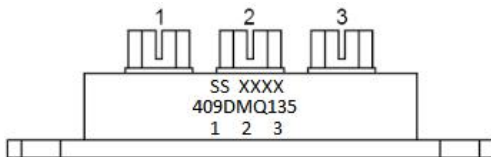
Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

Mechanical Dimensions PRM4 Isolated (Millimeters/Inches)



Please Note: Suffix "R" Denotes For Reversed Polarity

Marking Diagram



Where XXXX is YYWW

409DMQ135 = Part name
SS = SS
YY = Year
WW = Week

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping
409DMQ SERIES	PRM4 Isolated (Pb-Free)	9 pcs/box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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